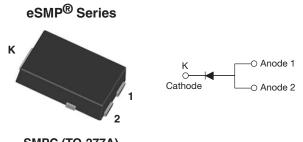
Vishay Semiconductors

Hyperfast Rectifier, 6 A FRED Pt[®]



www.vishay.com

SMPC (TO-277A)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)} 6 A						
V _R	600 V					
V _F at I _F	1.05 V					
t _{rr (typ.)}	33 ns					
T _J max.	175 °C					
Package	SMPC (TO-277A)					
Circuit configuration	Single					

FEATURES

Hyperfast recovery time, reduced Q_{rr}, and soft recovery



HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC, CRM/CCM, snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _{Sp} = 145 °C	6	٨		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	90	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-	
Forward voltage	V _F	I _F = 6 A	-	1.30	1.80	V
		I _F = 6 A, T _J = 150 °C	-	1.05	1.55	
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	5	
neverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	50	300	μA
Junction capacitance	CT	V _R = 600 V	-	8	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t$	= 50 A/ μ s, V _R = 30 V	-	33	-	
Reverse recovery time	+	$I_F = 0.5 \text{ A}, I_R =$	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A			40	20
Reverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	A
		T _J = 125 °C	I _F = 6 A dI _F /dt = 500 A/μs V _R = 400 V	-	75	-	
Deals recovers ourrent		T _J = 25 °C		-	6.8	-	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	11	-	A
	0	T _J = 25 °C		-	140	-	nC
Reverse recovery charge	Q _{rr}	$J_{\rm rr}$ T _J = 125 °C		-	400	-	nc

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to mount	R _{thJM}		-	2.4	3.5	°C/W	
Approximate weight				0.1		g	
				0.0035		oz.	
Marking device		Case style SMPC (TO-277A)		NE	:H6		

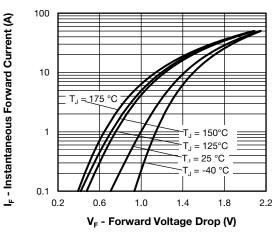


Fig. 1 - Typical Forward Voltage Drop Characteristics

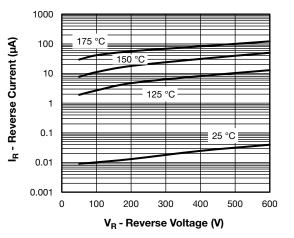
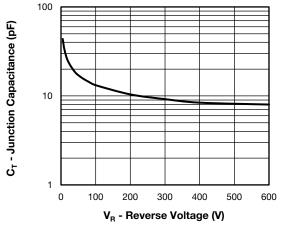


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

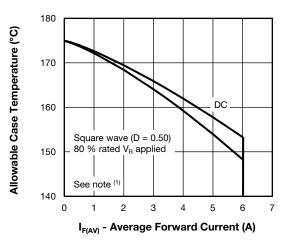


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

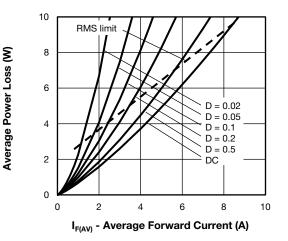


Fig. 5 - Forward Power Loss Characteristics

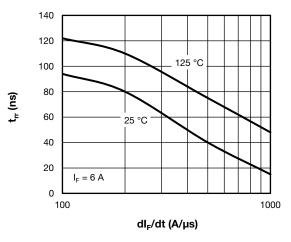


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

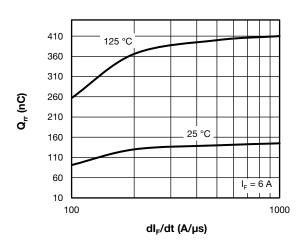


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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VS-6ESH06-M3

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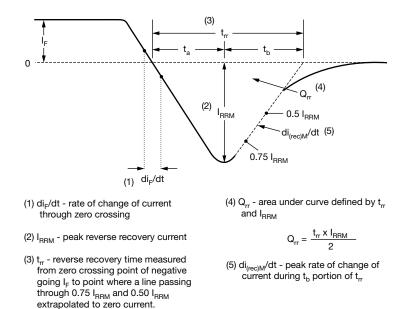


Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

SHAY

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Device code	VS-	6	Е	S	н	06	-M3
		2	3	4	5	6	7
	1 2 3	- Cur - Circ	rent rati cuit conf	niconduo ng (6 = 0 iguratior	6 A)	oduct	
		- S = - Pro	cess typ	package			
	6 · · · · · · · · · · · · · · · · · · ·	- Vol	tage coo	de (06 = gen-free	600 V)	complia	ant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-6ESH06-M3/86A	1500	1500	7" diameter plastic tape and reel				
VS-6ESH06-M3/87A	6500	6500	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				

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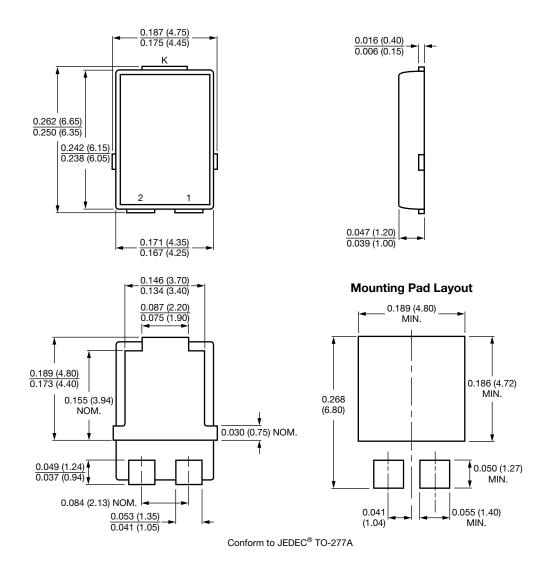
Outline Dimensions





SMPC (TO-277A)

DIMENSIONS in inches (millimeters)





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